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General Purpose Transistor

Symbol

VCEO

 V_{CBO}

 V_{EBO}

 I_{C}

 P_D

 P_D

 P_D

T_J, T_{sta}

Value

25

25

5.0

100

625

5.0

450

1.5

12

-55 to +150

Unit

Vdc

Vdc

Vdc

mAdc

mW

mW/⁰C

mW

W

mW/⁰C

°C

NPN Silicon

MAXIMUM RATINGS

Collector-Emitter Voltage

Collector-Base Voltage

Collector Current - Continuous

Total Device Dissipation @ T_A = 25°C

Total Power Dissipation @ $T_A = 60^{\circ}C$

Total Device Dissipation @ T_C = 25°C Derate above 25°C

Operating and Storage Junction

Emitter-Base Voltage

Derate above 25°C

Temperature Range

Features

• Pb-Free Packages are Available*

Rating

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http://onsemi.com





THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

MARKING DIAGRAM



MPS5172 = Device Code = Assembly Location А Y = Year WW

= Work Week

.

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping
MPS5172	TO-92	5000 / Bulk
MPS5172G	TO–92 (Pb–Free)	5000 / Bulk
MPS5172RLRM	TO-92	2000/Ammo Pack
MPS5172RLRMG	TO–92 (Pb–Free)	2000/Ammo Pack

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage (Note 1) $(I_C = 10 \text{ mA}, I_B = 0)$	V _{(BR)CEO}	25	-	Vdc
Collector Cutoff Current ($V_{CE} = 25 \text{ V}, I_B = 0$)	I _{CES}	-	100	nAdc
Collector Cutoff Current $(V_{CB} = 25 \text{ V}, I_E = 0)$ $(V_{CB} = 25 \text{ V}, I_E = 0, T_A = 100^{\circ}\text{C})$	I _{CBO}		100 10	nAdc μAdc
Emitter Cutoff Current ($V_{EB} = 5.0 \text{ V}, I_C = 0$)	I _{EBO}	-	100	nAdc
ON CHARACTERISTICS (Note 1)	·			
DC Current Gain (V_{CE} = 10 V, I _C = 10 mA)	h _{FE}	100	500	-
Collector-Emitter Saturation Voltage (I _C = 10 mAdc, I _B = 1.0 mAdc)	V _{CE(sat)}	-	0.25	Vdc
Base – Emitter On Voltage ($I_C = 10 \text{ mAdc}, V_{CE} = 10 \text{ V}$)	V _{BE(on)}	0.5	1.25	Vdc
SMALL-SIGNAL CHARACTERISTICS		·		<u> </u>
Collector–Base Capacitance (V_{CB} = 10 V, f = 1.0 MHz)	C _{cb}	1.6	10	pF
Small–Signal Current Gain (I _C = 10 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{fe}	100	750	-

1. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

TYPICAL STATIC CHARACTERISTICS



TYPICAL DYNAMIC CHARACTERISTICS



Figure 6. Current-Gain – Bandwidth Product

Figure 7. Capacitance



Figure 8. Thermal Response



Figure 10.



Figure 11.

DESIGN NOTE: USE OF THERMAL RESPONSE DATA

A train of periodical power pulses can be represented by the model as shown in Figure 9. Using the model and the device thermal response the normalized effective transient thermal resistance of Figure 8 was calculated for various duty cycles.

To find $Z_{\theta JA(t)}$, multiply the value obtained from Figure 8 by the steady state value $R_{\theta JA}$.

Example: The MPS3904 is dissipating 2.0 watts peak under the following conditions:

 $t_1 = 1.0 \text{ ms}, t_2 = 5.0 \text{ ms}. (D = 0.2)$

Using Figure 8 at a pulse width of 1.0 ms and D = 0.2, the reading of r(t) is 0.22.

The peak rise in junction temperature is therefore

 $\Delta T = r(t) \ge P_{(pk)} \ge R_{\theta JA} = 0.22 \ge 2.0 \ge 200 = 88^{\circ}C.$

For more information, see ON Semiconductor Application Note AN569/D, available from the Literature Distribution Center or on our website at www.onsemi.com.

The safe operating area curves indicate I_C-V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 11 is based upon $T_{J(pk)} = 150^{\circ}$ C; T_{C} or T_{A} is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}$ C. $T_{J(pk)}$ may be calculated from the data in Figure 8. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL**





NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2 3.
- T14.30M, 1982. Controlling Dimension: Inch. Contour of Package Beyond Dimension R Is uncontrolled. Lead Dimension Is uncontrolled in P and 4. BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
C	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
Ν	0.080	0.105	2.04	2.66	
Ρ		0.100		2.54	
R	0.115		2.93		
V	0.135		3.43		

STYLE 1: PIN 1. EMITTER

2. BASE COLLECTOR 3.

3. SOURCE

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